UNITED STATES PATENT AND TRADEMARK OFFICE CERTIFICATE OF CORRECTION

PATENT NO. : 6,921,914 B2 APPLICATION NO. : 10/802185

: July 26, 20005

DATED INVENTOR(S)

: Cheng et al.

It is certified that error appears in the above-identified patent and that said Letters Patent is hereby corrected as shown below:

Title page and Col. 1, Ln. 1, replace current title with -- SEMICONDUCTOR SUBSTRATE STRUCTURE--

Column 1, between lines 14, ending "herein.", and line 16, beginning "BACKGROUND OF", insert the following paragraph:

--GOVERNMENT LICENSE RIGHTS

This invention was made with government support under Contract Number N66001-00-1-8954, awarded by the Navy. The government has certain rights in the invention.--

Signed and Sealed this

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Nineteenth Day of June, 2007

JON W. DUDAS
Director of the United States Patent and Trademark Office